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Bib Data Sheet

CONFIRMATION NO. 2372

SERIAL NUMBER 10/821,944	FILING DATE 04/12/2004 RULE	CLASS 438	GROUP ART UNIT 2818	ATTORNEY DOCKET NO. Q81061
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APPLICANTS

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** CONTINUING DATA *****
 This application is a CON of 09/473,708 12/29/1999 PAT 6,719,842
 which claims benefit of 60/114,376 12/30/1998

** FOREIGN APPLICATIONS *****
 JAPAN HEI. 10-253027 09/07/1998

IF REQUIRED, FOREIGN FILING LICENSE GRANTED
 ** 06/21/2004

Foreign Priority claimed 35 USC 119 (a-d) conditions met Verified and Acknowledged	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance Examiner's Signature _____ Initials _____	STATE OR COUNTRY JAPAN	SHEETS DRAWING 2	TOTAL CLAIMS 1	INDEPENDENT CLAIMS 1
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TITLE
 Ammonia for use in manufacture of GaN-type compound semiconductor and method for manufacturing GaN-type compound semiconductor

FILING FEE	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time)
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